



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max (A) T _A = +25°C	
-40V	25mΩ @ V _{GS} = -10V	-7.2A	
	45mΩ @ V _{GS} = -4.5V	-5.3A	

Description and Applications

This new generation MOSFET has been designed to minimize the onstate resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Motor controls
- Backlighting
- **DC-DC** converters
- Printer equipment

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low R_{DS(ON)} Minimizes Conduction Losses
- Fast Switching Speed Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Qsuffix) part. A listing can be found at https://www.diodes.com/products/automotive/automotiveproducts/.
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

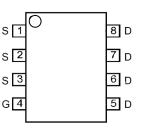
https://www.diodes.com/quality/product-definitions/

Mechanical Data

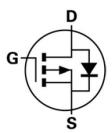
- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.074 grams (Approximate)



Top View



Pin-Out Top View



Internal Schematic

Ordering Information (Note 4)

Part Number	Bookago	Packing			
Part Number	Package	Qty.	Carrier		
DMP4026LSS-13	SO-8	2,500	Reel		

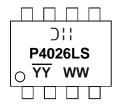
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



∃ = Manufacturer's Marking P4026LS = Product Type Marking Code YYWW = Date Code Marking \overline{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	-40	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = -10V	Steady State	T _A = +25°C T _A = +70°C	lo	-7.2 -5.7	А
Maximum Body Diode Forward Current (Note 6)			ls	-7.2	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	-46	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	-46	A
Avalanche Current, L = 0.3mH			las	-20	А
Avalanche Energy, L = 0.3mH			E _{AS}	62	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

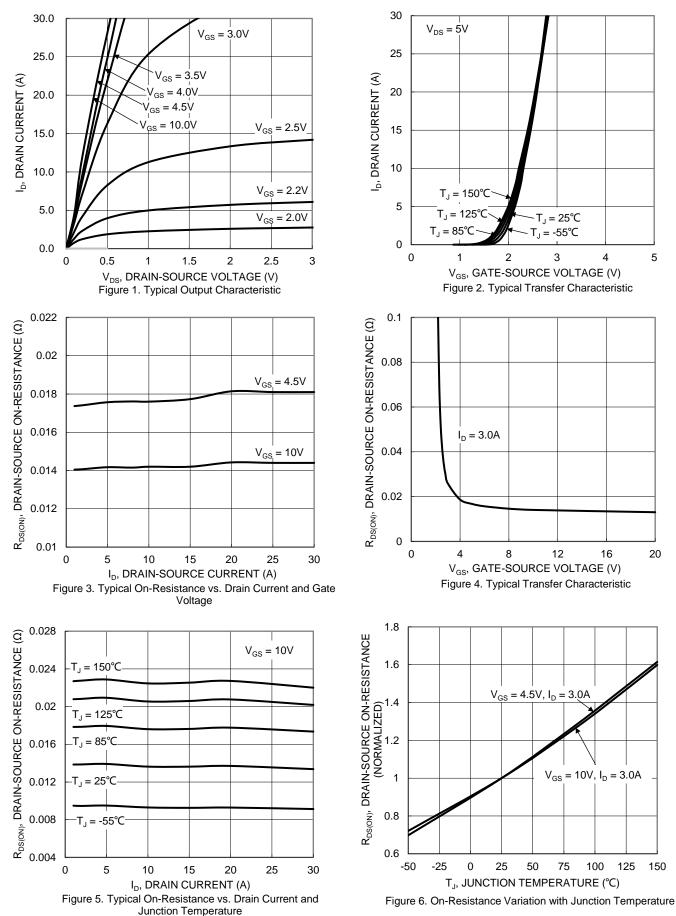
Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1.5	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	82.7	°C/W	
Total Power Dissipation (Note 6)		PD	2.0	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	60.3	°CAN	
Thermal Resistance, Junction to Case		Rejc	8.2	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	2				1		
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						·	
Gate Threshold Voltage	Vgs(th)	-0.8	—	-1.8	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	D	_	13.9	25	mΩ	$V_{GS} = -10V, I_D = -3A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	17.2	45	mΩ	V _{GS} = -4.5V, I _D = -3A	
Diode Forward Voltage	Vsd	_	-0.7	-1.0	V	VGS = 0V, IS = -1A	
DYNAMIC CHARACTERISTICS (Note 8)						·	
Input Capacitance	Ciss		2083			V _{DS} = -20V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss		221	_	pF		
Reverse Transfer Capacitance	Crss	_	191	_			
Gate Resistance	Rg	_	2.5	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (V _{GS} = -10V)	Q_{G}	_	45	_		V _{DS} = -20V. I _D = -3A	
Total Gate Charge (V _{GS} = -4.5V)	QG	_	23.5	_	nC		
Gate-Source Charge	QGS	_	5	_	nc	$V_{DS} = -20V, I_D = -3A$	
Gate-Drain Charge	Qgd	_	6.7	_			
Turn-On Delay Time	td(ON)	_	4.3	_		$V_{GS} = -10V, V_{DD} = -20V, R_G = 6\Omega,$	
Turn-On Rise Time	tR	_	4.8	_			
Turn-Off Delay Time	tD(OFF)	_	71	_	ns	I _D = -3A	
Turn-Off Fall Time	tF		24	_			
Body Diode Reverse Recovery Time	trr		17.3	_	ns	Is = -3A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	QRR	_	8.7	_	nC	Is = -3A, di/dt = 100A/µs	

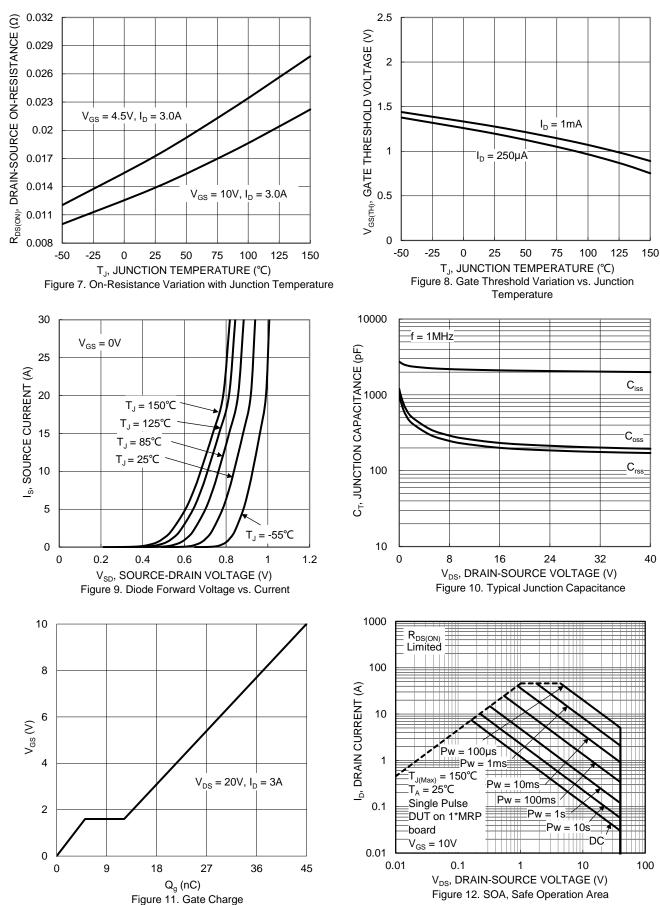
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:





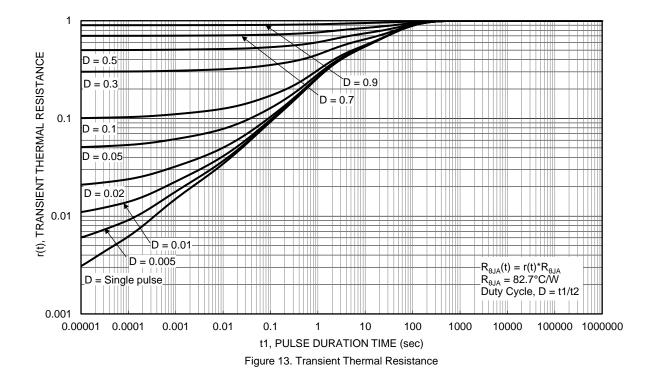
DMP4026LSS Document number: DS44828 Rev: 2 - 2





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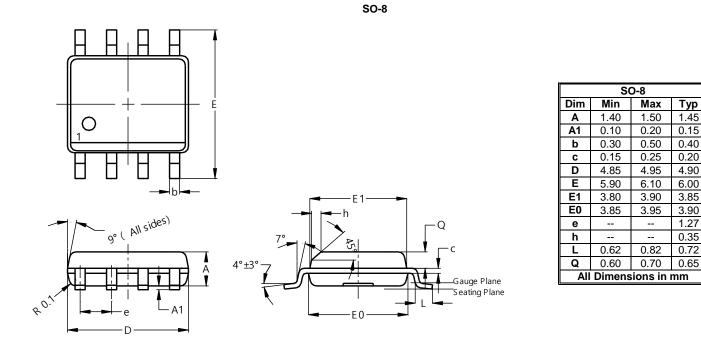






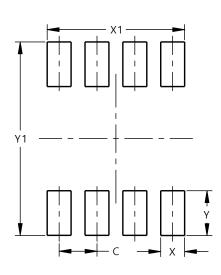
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

SO-8



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